

Technical Data Sheet

3mm Silicon PIN Photodiode T-1

PT340\C

Features

- Fast response time
- High photo sensitivity
- Small junction capacitance
- Pb free

Descriptions

PT340\C is a high speed and high sensitive PIN photodiode in a standard 3 Φ plastic package. Due to its water clear epoxy the device is sensitive to visible and infrared radiation.



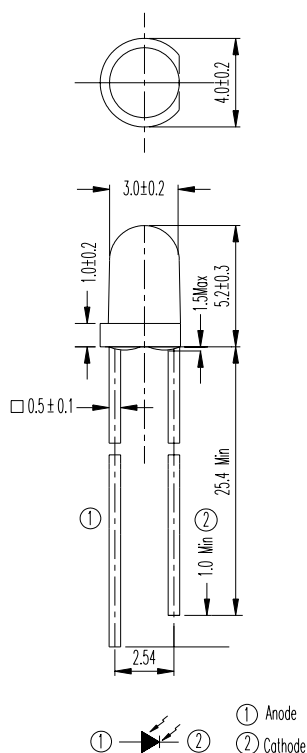
Applications

- Automatic door sensor
- Camera
- Game machine
- High speed photo detector

Device Selection Guide

LED Part No.	Chip	Lens Color
	Material	
PT	Silicon	Water clear

Package Dimensions



Notes: 1.All dimensions are in millimeters
2.Tolerances unless dimensions $\pm 0.25\text{mm}$

Absolute Maximum Ratings ($T_a=25^\circ\text{C}$)

Parameter	Symbol	Rating	Units
Reverse Voltage	V_R	32	V
Operating Temperature	T_{opr}	$-25 \sim +85$	$^\circ\text{C}$
Storage Temperature	T_{stg}	$-40 \sim +85$	$^\circ\text{C}$
Soldering Temperature	T_{sol}	260	$^\circ\text{C}$
Power Dissipation at(or below) 25°C Free Air Temperature	P_c	150	mW

Notes: *1:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Rang Of Spectral Bandwidth	$\lambda_{0.5}$	---	400	---	1100	nm
Wavelength Of Peak Sensitivity	λ_p	---	---	940	---	nm
Open-Circuit Voltage	V_{OC}	Ee=5mW/cm ² $\lambda_p=940\text{nm}$	---	0.44	---	V
Short- Circuit Current	I_{SC}	Ee=1mW/cm ² $\lambda_p=940\text{nm}$	---	10	---	μA
Reverse Light Current	I_L	Ee=1mW/cm ² $\lambda_p=940\text{nm}$ $V_R=5\text{V}$	---	10	---	μA
Reverse Dark Current	I_D	Ee=0mW/cm ² $V_R=10\text{V}$	---	---	10	nA
Reverse Breakdown Voltage	B_{VR}	Ee=0mW/cm ² $I_R=100\mu\text{A}$	32	170	---	V
Total Capacitance	C_t	Ee=0mW/cm ² $V_R=5\text{V}$ $f=1\text{MHz}$	---	10	---	pF
Rise Time	t_r	$V_R=10\text{V}$ $R_L=100\Omega$	---	10	---	nS
Fall Time	t_f		---	10	---	

Typical Electro-Optical Characteristics Curves

Fig.1 Power Dissipation vs.
Ambient Temperature

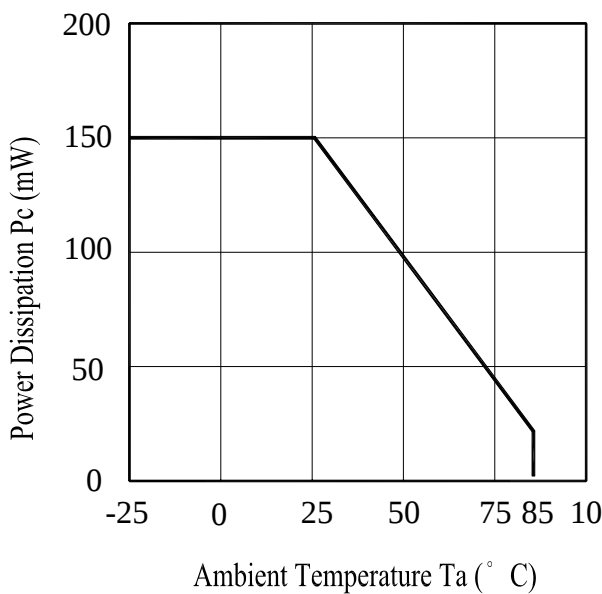


Fig.2 Spectral Sensitivity

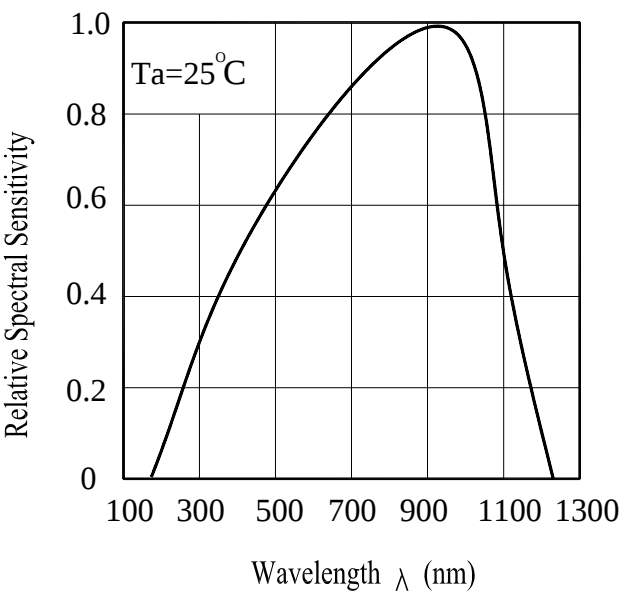


Fig.3 Dark Current vs.
Ambient Temperature

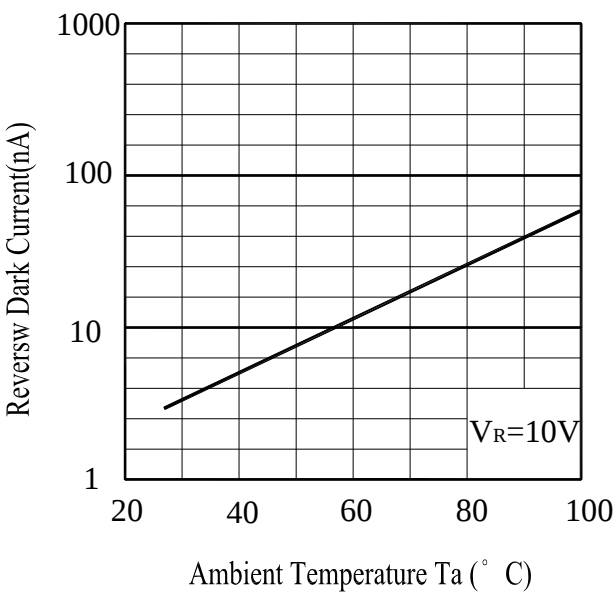
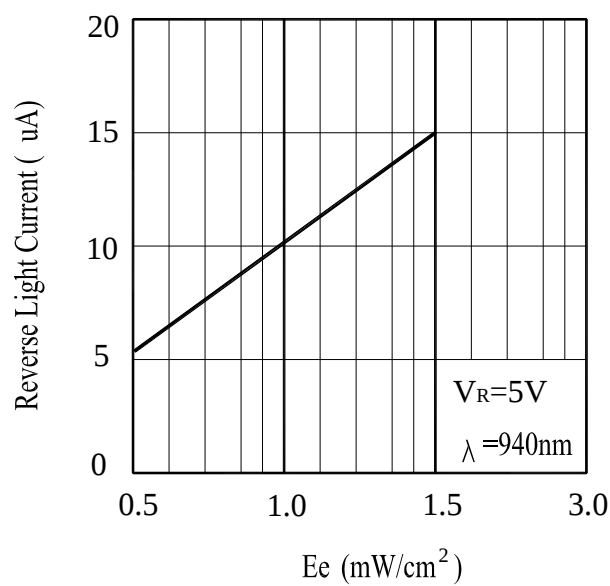


Fig. 4 Reverse Light Current vs.
 E_e



Typical Electro-Optical Characteristics Curves

Fig.5 Terminal Capacitance vs.

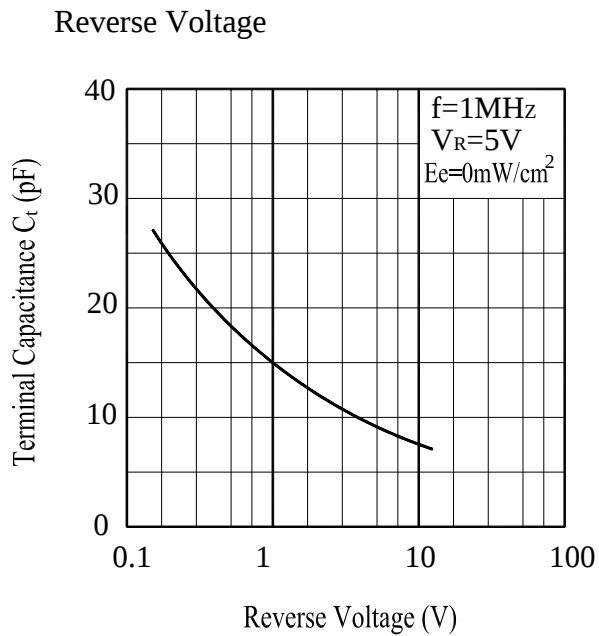
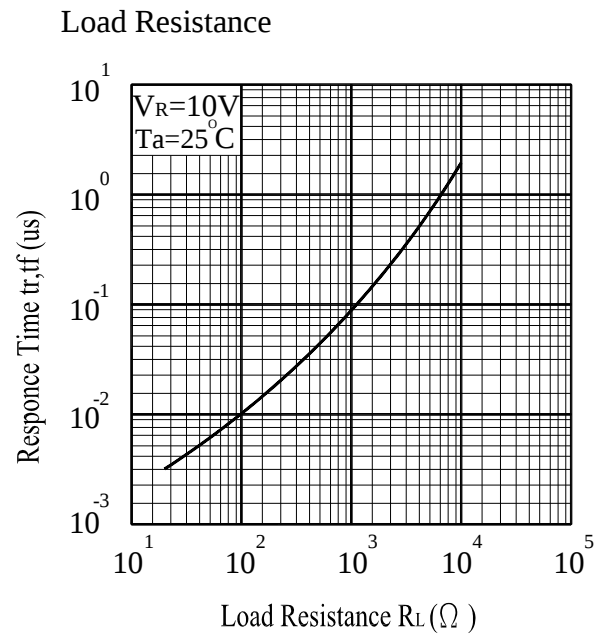


Fig.6 Response Time vs.



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP. : $260^{\circ}\text{C} \pm 5^{\circ}\text{C}$	10secs	22pcs	$I_L \leq L \times 0.8$ L : Lower Specification Limit	0/1
2	Temperature Cycle	H : $+100^{\circ}\text{C}$ 15mins $\updownarrow$ 5mins L : -40°C 15mins	50Cycles	22pcs		0/1
3	Thermal Shock	H : $+100^{\circ}\text{C}$ 5mins $\updownarrow$ 10secs L : -10°C 5mins	50Cycles	22pcs		0/1
4	High Temperature Storage	TEMP. : $+100^{\circ}\text{C}$	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000hrs	22pcs		0/1
6	DC Operating Life	$V_R = 5\text{V}$	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1